

## Features

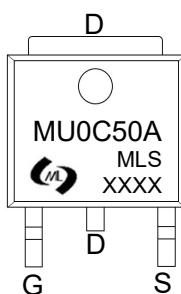
- High density cell design for ultra low  $R_{DS(on)}$
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high  $E_{AS}$
- Excellent package for good heat dissipation

## Product Summary

$V_{DS}$	$R_{DS(ON)\ MAX}$	$I_D\ MAX$
20V	10mΩ@10V	50A
	13mΩ@4.5V	

## Application

- Load switching
- Hard switched and high frequency circuits
- Uninterruptible power supply

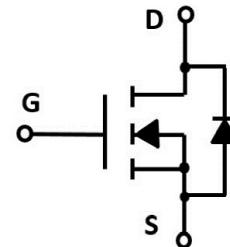


MU0C50A: Device code  
XXXX: Code

Marking and pin assignment



TO-252 top view



Schematic diagram



Halogen-Free

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit	
<b>Common Ratings (TC=25°C Unless Otherwise Noted)</b>				
$V_{DS}$	Drain-Source Breakdown Voltage	20	V	
$V_{GS}$	Gate-Source Voltage	±12	V	
$T_J$	Maximum Junction Temperature	150	°C	
$T_{STG}$	Storage Temperature Range	-50 to 155	°C	
$I_S$	Diode Continuous Forward Current	50	A	
<b>Mounted on Large Heat Sink</b>				
$I_{DM}$	Pulse Drain Current Tested	Tc=25°C	200	A
$I_D$	Continuous Drain Current	Tc=25°C	50	A
$P_D$	Maximum Power Dissipation	Tc=25°C	31	W
$E_{AS}$	Single pulse avalanche energy		11.25	mJ

## Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MU0C50A	TO-252	MU0C50A	2,500	5,000	35,000	13"reel

**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	20	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	--	--	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±12V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	0.45	0.75	1.2	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	--	6.8	10	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =18A	--	8	13	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =5A	--	12	19	mΩ
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHz	--	1613	--	pF
C <sub>OSS</sub>	Output Capacitance		--	228	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	200	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =10V, I <sub>D</sub> =25A, V <sub>GS</sub> =4.5V	--	18	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	3.5	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	5.5	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =10V, I <sub>D</sub> =25A, V <sub>GS</sub> =4.5V, R <sub>G</sub> =3Ω	--	9	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	19	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	38	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	24	--	nS
<b>Source- Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>j</sub> =25°C, I <sub>S</sub> =10A	--	--	1.2	V

### Typical Operating Characteristics

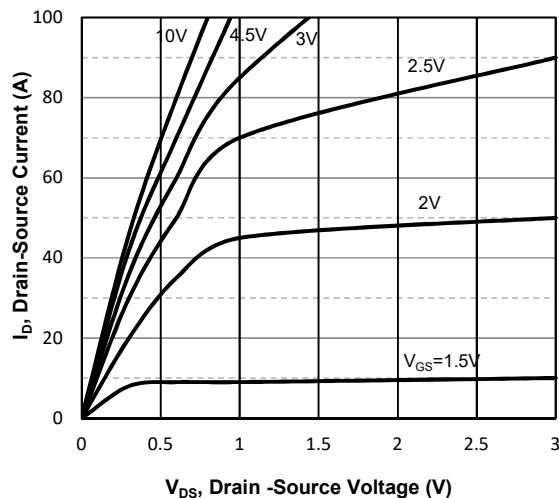


Fig1. Typical Output Characteristics

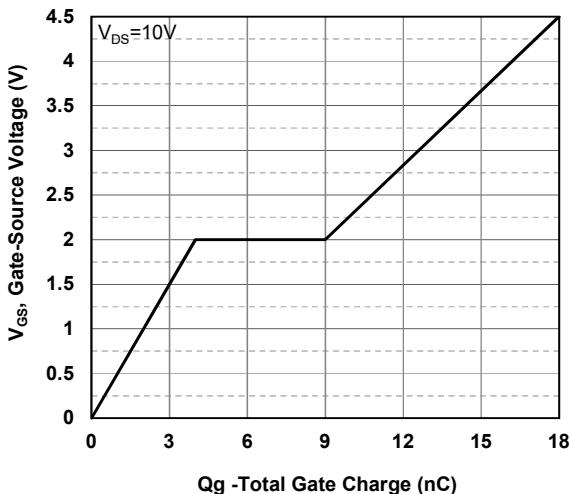


Fig2. Typical Gate Charge Vs.Gate-Source Voltage

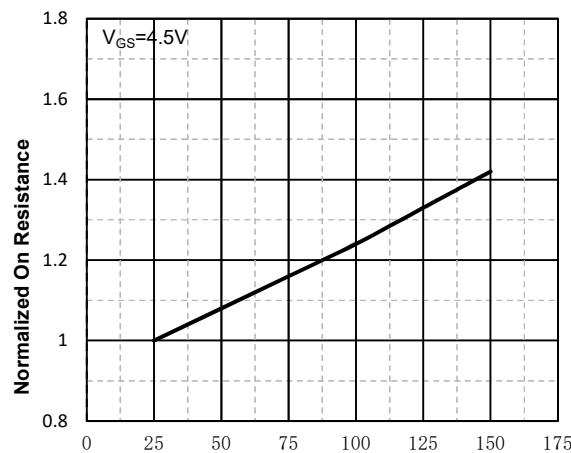


Fig3. Normalized On-Resistance Vs. Temperature

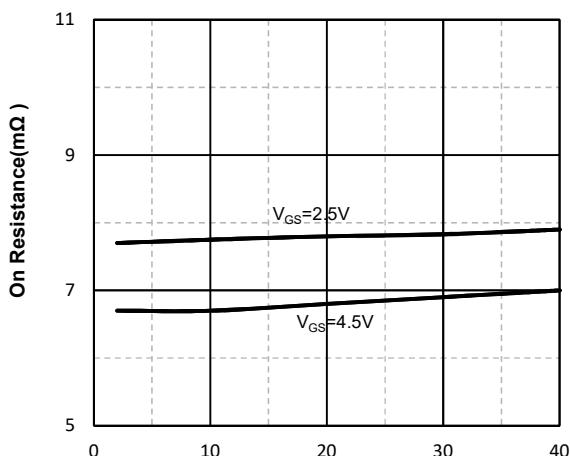


Fig4. On-Resistance Vs. Drain-Source Current

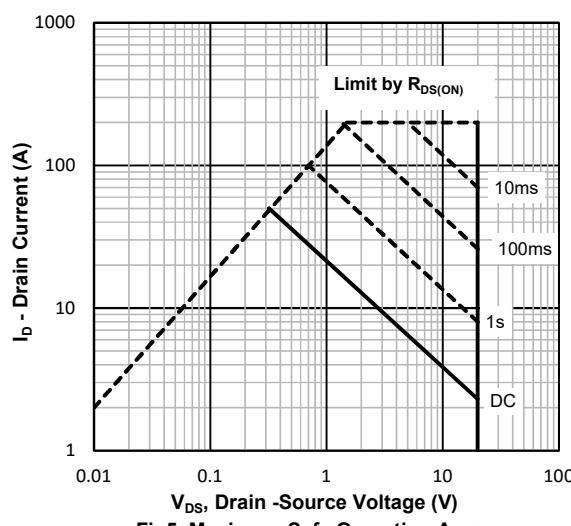


Fig5. Maximum Safe Operating Area

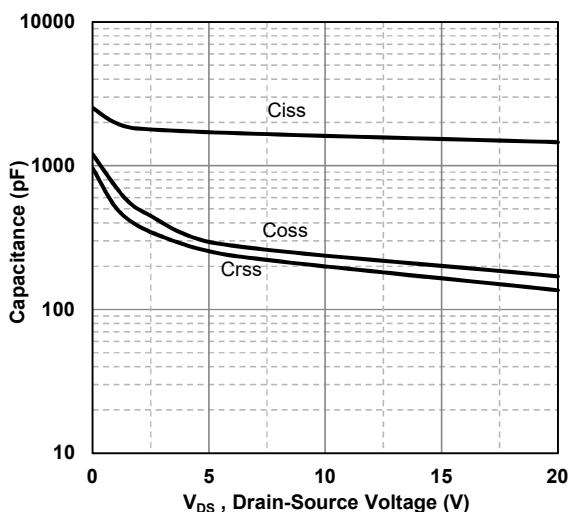
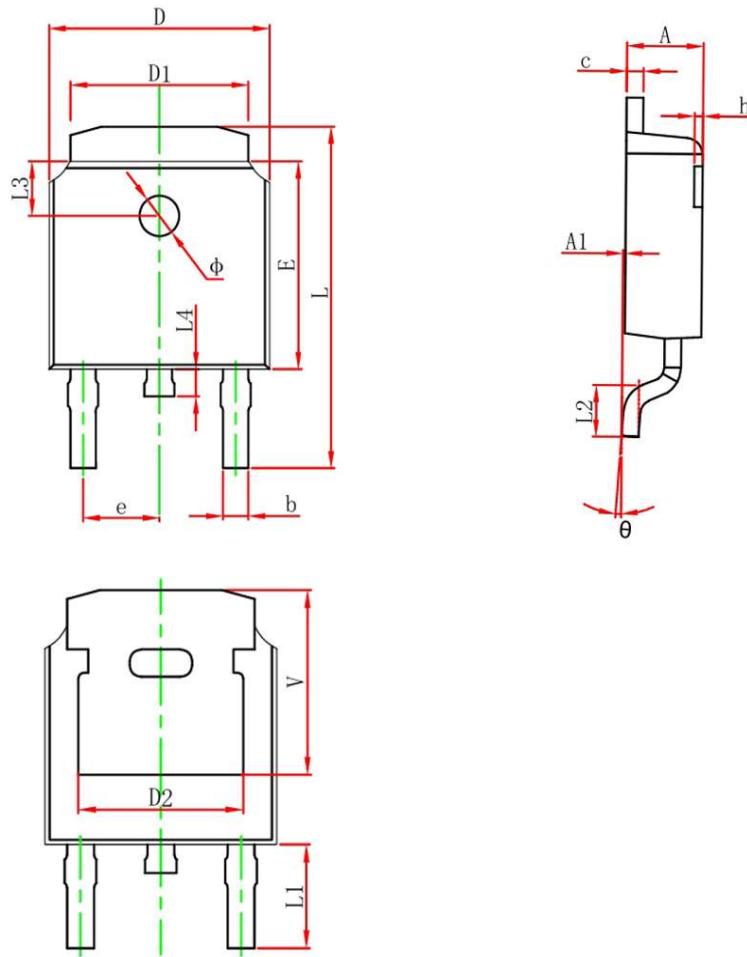


Fig6 Typical Capacitance Vs.Drain-Source

## TO-252 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.635	0.770	0.025	0.030
c	0.450	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.712	10.312	0.386	0.406
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.250 REF.		0.207 REF.	